CSP20C04/CSB20C04



PRELIMINARY

20 AMPS. SCHOTTKY BARRIER RECTIFIERS

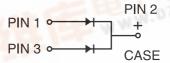
FEATURES

- Metal of silicon rectifier, major carrier conduction
- Low power loss, high efficient
- High current capability, low V_F









MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Tc=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Maximum Recurrent Peak Voltage	VRRM	40	V
Maximum RMS Voltage	VRMS	28	V c
Maximum DC Blocking Voltage	VDC	40	AI-DA
Maximum Average Forward Rectified Current at Tc=95°C	I F(AV)	20	А
Peak Forward SurgeCurrent, 8.3ms single half sine- wave superimposed on rated load (JEDEC Method)	FSM	250	А
Maximum Forward Voltage IF=8A, Tc=25°C	VF	0.60	V
Maximum Reverse Current at Peak Reverse Voltage ^a	lR	1	mA
Typical Thermal Resistance, Junction-to-Case	$R\theta JC$	2	°C/W
Typical Junction Capacitance, VR=4V	CJ	650	pF
Maximum Operating Junction Temperature	TJ	-65 to 125	°C
Maximum Storage Temperature	Тѕтс	-65 to 150	°C

NOTEE:a. Test Pulse Width 300us, Duty Cyale 2%

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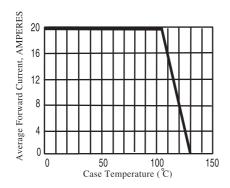


Figure 1. Forward Current Derating Curve

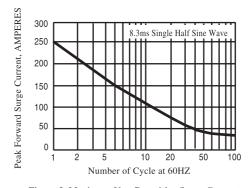
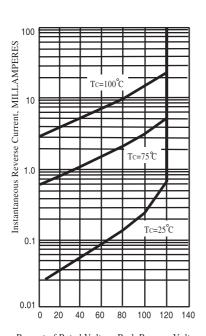
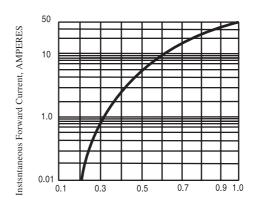


Figure 3. Maximum Non-Repetitive Surge Current



Percent of Rated Voltage Peak Reverse Voltage

Figure 2. Typical Reverse Characteristics



Instantaneous Forward Voltage (V)

Figure 4. Typical Instantaneous Forward Characteristics

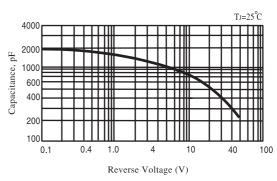


Figure 5. Typical Junction Capacitance